Therm oelectric properties of the brownm illerite oxide Ca₂ vLavCo₂ xA lxO 5

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W e prepared the brownm illerite oxide $Ca_{2 y} La_{y}Co_{2 x} A \downarrow_{x}O_{5}$, and found that it was an n-type conductor. The therm opower and the resistivity of the single crystal are 90 V/K and 68 m cm along the abdirection at 440 K, which suggest relatively good therm oelectrical properties, com pared with other transition-m etal oxides. Their tem perature dependences are of activation type, and the activation energies are 0.2 eV for the resistivity and 0.04 eV for the therm opower. These energies di er by one order in m agnitude, which in plies that a polaron dom inates the charge transport. A sign of the therm opower of the polycrystals changes from negative to positive at 500 K, indicating that holes are excited therm ally to decrease the m agnitude of therm opower.

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I. IN TRODUCTION

Therm oelectric materials, which convert heat into electricity and vice versa through the therm oelectric phenomena in solids, have recently attracted a renewed interest as a promising energy-conversion technology that is friendly to the environment. The conversion e ciency of a therm celectric material is characterized by the gure of merit $Z = S^2 =$, where S, and are the therm opower, the resistivity, and the thermal conductivity, respectively.

Recently Terasakiet al.[1] found that a layered cobalt oxide N aC o_2O_4 shows a large therm opower of 100 V/K and a low resistivity of 200 cm at room temperature, and they proposed that the strong correlation plays an important role in the enhancement of the therm oelectric properties. B assed on this proposal, other layered cobalt oxides B iSr-C o-O [2, 3] and C a-C o-O [4, 5, 6] have been studied, and they are found to be potential therm oelectric m aterials as well as N aC o_2O_4 . In particular, Funahashiet al.[6] reported them axim um of Z T is larger than 1.2 for C a-C o-O, which m eans that the layered cobalt oxidesm ight be the best group am ong all the therm oelectric m aterials.

These layered cobalt oxides are, however, all p-type m aterials, and an n-type cobalt oxide has not been found yet. Therm oelectric devices are made from a pair of p and n-type therm oelectric materials, and we tried to nd an n-type cobalt oxide. The Co ion in NaCo₂O₄ is at the center of an oxygen octahedron, and its average valence is + 3.5 with the electron con guration of $(3d)^{5:5}$, which corresponds to 0.5 hole in the t_{2g} bands per Co site. In NaCo₂O₄, the octahedron is edge-shared, where the t_{2g} bands of Co 3d directly overlap each other. By contrast, electrons doped in an insulating cobalt oxide

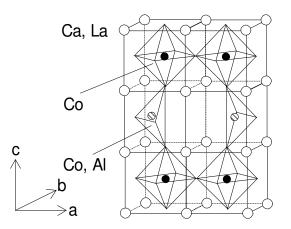
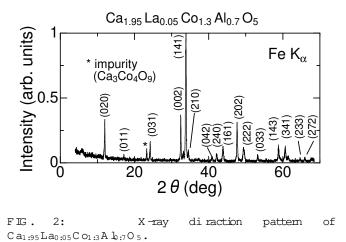


FIG.1: Schem atic view of the brownm illerite structure.

m ade of C o^{3+} will be in the e_g bands. Since the e_g bands are strongly hybridized with 0 2p, the conduction-band width is largest when the bonding angle of C o-O -C o is 180. Thus a cobalt oxide in a corner-shared oxygen octahedron will be a good n-type conductor.

A coordingly we searched for a cobalt oxide in a comer-shared oxygen octahedron, and eventually found Ca_2 (Co,Al)₂O₅[7], which has a brownm illerite structure with Co^{3+} . The brownm illerite structure is schematically shown in Fig. 1. Big white circles represent Ca and La, black circles Co, shaded circles Al and Co. This structure is composed of an alternate stack of the CoO_2 square lattice and the (Co,Al)O chain along the c direction, and can be regarded as an oxide-de cient perovskite structure. In this paper we report on preparation of polycrystalline and single-crystal sam ples, and on m easurem ents and analyses of their therm oelectric properties.

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II. EXPERIMENTAL

Polycrystalline sam ples of Ca₂ y La_yCoA D₅ (y = 0, 0.05, 0.1 and 0.15) and Ca_{1:95}La_{0:05}Co₂ x A l_xO_5 (x = 0.4, 0.5, 0.6, and 0.7) were prepared by a solid-state reaction. Stoichiom etric amounts of CaCO₃, La₂O₃, Co₃O₄ and A l_2O_3 were m ixed, and the m ixture was calcined at 900 C for 12h in air. The product was nely ground, pressed into a pellet, and sintered at 960 C for 12h in air.

Single-crystal samples were prepared by a $B_{12}O_3/PbO$ ux method. $B_{12}O_3$, PbO, $CaCO_3$ and Co_3O_4 powders were mixed with a cationic composition of $B_{12}B_{D}CaCo=1.3.0.7.3.2$, and was heated at 1100 C for 5h, and then slow ly cooled down to 700 C at a rate of 8 C/h in air using an $A_{12}O_3$ crucible (Alwas supplied from the crucible). The composition ratio of a singlecrystal samplem easured by energy dispersive X-ray analysis (EDX) is CaCoA = 21.3.0.7.

The X-ray di raction (XRD) of the sample was measured using a standard di ractom eter with Fe K radiation as an X-ray source in the 2 scan mode. The resistivity was measured using a four-probe method, below room temperature in a liquid He cryostat, and above room tem perature in an electric furnace. The therm opower was measured using a steady-state technique, below room temperature in a liquid He cryostat, and above room tem perature in an electric furnace. A tem perature gradient of 1 K /cm was generated by a small resistive heater pasted on one edge of a sample, and was monitored by a di erential therm occuple made of copper-constantan below room tem perature, and by that ofplatinum -rhodium above room tem perature. The therm opower of the voltage leads was carefully subtracted. The therm alconductivity wasm easured from 30 to 280 K using a steady-state technique in a closed refrigerator pum ped down to 10⁶ Torr. The tem perature gradient wasm onitored using a di erential therm occuple m ade of chrom el-constantan.

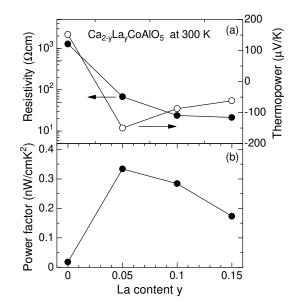


FIG. 3: (a) Resistivity and the thermopower of C a_2 $_y$ La_yCOA lo $_5$ at 300 K and (b) power factor of C a_2 $_y$ La_yCOA lo $_5$ at 300K.

III. RESULTS AND DISCUSSION

Figure 2 shows an XRD pattern of a polycrystalline sample Ca_{1:95}La_{0:05}Co_{1:3}Al_{0:7}O₅ A small amount (at most 7%) of impurity phase (mainly Ca₃Co₄O₉) [5] is seen, but alm ost all the peaks are indexed as the brownm illerite phase. The lattice parameters were obtained to be a = 5.28 A, b = 5.52 A, and c = 14.66 A, which is consistent with a 4-cycle X-ray di raction of a single crystal. W e will use the composition as the nom inal composition in the present paper, though the real com position is different from the nom inal com position. How ever, the difference is smallwithin less than 10% accuracy: for exam ple a nom inalLa [A 1] content of 0.05 [0.5] corresponds to 0.053 [0.54] for the real com position at most. W e further note that the impurity phase of Ca₃Co₄O₉ shows positive and nearly tem perature-independent therm opower above 100 K [5], which would not seriously a ect the tem perature and the composition dependences of and S, or the discussion in the present paper.

Figure 3(a) shows and S of polycrystalline $Ca_{2 y} La_y CoA D_5$ at room temperature. W ith increasing La content y, decreases system atically, and the sign of S changes from positive to negative. This indicates that the substitution of La^{3+} for Ca^{2+} supplies an electron. Figure 3(b) shows the power factor $S^{2=}$ corresponding to the data in Fig 2(a). The power factor takes a m aximum at y=0.05, and accordingly we x y to be 0.05 to see the A L-content dependence.

Figure 4(a) shows of polycrystalline samples of $Ca_{1:95}La_{0:05}Co_{2 x} Al_xO_5$, together with the in-plane (parallel to the ab direction) and the out-of-plane (parallel to the c direction) resistivity of a single-crystal sample of $Ca_2Co_{1:3}Al_{0:7}O_y$. At 750 K, the magnitude of resis-

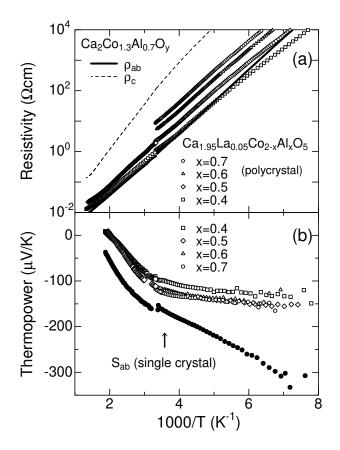


FIG. 4: (a) Resistivity and (b) thermopower of polycrystalline $Ca_{1.95}La_{0.05}Co_{2 \times}A \downarrow_{x}O_{5}$ and single-crystal $Ca_{2}Co_{1:3}A \downarrow_{0:7}O_{y}$

tivity decreases down to 10-20 m cm for polycrystalline sam ples and the in-plane direction of the single crystals. This magnitude of resistivity is the lowest, to our know edge, in brow nm illerite oxides [8, 9]. The tem perature dependence is described by an activation-type conduction, where the activation energy for resistivity (E) is approxin ately 0.2 eV for all the sam ples. As for an isotropy, the out-of-plane resistivity is 100 times higher than that for the in-plane resistivity, in plying that the layered structure is realized, as is expected from the brownm illerite phase. This means that the conduction path of a single crystal sample is two-dimensional, and the conduction path of the polycrystalline sam ples is mainly determ ined by the in-plane conduction paths. Then the resistivity of the polycrystalline samples is higher than the in-plane resistivity of the single crystal sample, while the tem perature dependences are similar, as is also seen in the resistivity of high-tem perature superconductors. The resistivity increases with increasing Al content x, which indicates that a C o ion is responsible for the electric conduction and an Alion acts as an impurity. We should note that the brownm illerite structure was not synthesized for x 0:4, which means that an Alion is essential to stabilizing the brow nm illerite structure at am bient pressure.

Figure 4(b) shows the therm opower of the prepared sam ples. The in-plane therm opower of the single-crystal sam ple is 150 V/K, and that of polycrystalline sam – ples is about 100 V/K at 300 K. This means that the carrier concentration of the single-crystal sam ple is sm aller than that of the polycrystalline sam ples, because no donor ion such as La is included in the single crystal. The source of the carrier is not clear at present, and the oxygen de ciency or a sm all inclusion of B 3 ⁺ are possible candidates.

It should be emphasized that the magnitude and the tem perature dependence of the therm opower of polycrystalline samples are nearly independent of x. Considering the x dependence of and S, we can conclude that an Alion acts as a scattering center (disorder) for electric conduction, although it stabilizes the brow nm illerite structure at ambient pressure [7]. Consequently carriers are likely to conduct on CoO₂ square lattice, not on the (Co,Al)O chain. Below 350 K, the temperature dependence of the therm opower is described by an activation-type conduction with the activation energy for therm opower (E_s) of 0.01 eV for the polycrystalline sam ples, and 0.04 eV for the single-crystal sam ple. E (= 02 eV) E_s (= 0:01 0:04 eV) implies a polaron conduction, where E $\,$ and E $_{\rm s}$ are described as $E_c + W_H$ and $E_s = E_F$ E_c (E_c : the en- $E = E_F$ ergy of bottom of conduction band, E_F : Ferm i energy, $W_{\rm H}$: hopping energy that contributes to the change of m obility by tem perature) [10]. Such a material is useful for the high-tem perature therm oelectric application [11], because a rapid decrease in and a gradual decrease in S will occur with increasing tem perature.

For the present m aterial, how ever, the high tem perature them opower is quite sm all. Above 350 K it deviates from the activation type, and the sign of the them opower of the polycrystalline samples changes from negative to positive at 500 K. A similar tendency was observed for the single-crystal sample, though a sign change was not yet seen below 550 K. As a result the therm oelectric perform ance rapidly decreases above 450 K. Very recently U eno et al. have found a similar sign change of the therm opower in the brownm illerite Ca-Co-A HO thin Im [12].

Figure 5 shows the therm al conductivity of polycrystalline samples. The magnitude is about 20 mW /cmK, which is relatively low, possibly due to a solid solution of C o and A L U sing = 20 mW /cmK, the gure of merit for x = 0.4 is estimated to be of the order of 10 6 K 1 at 300 K, which is three orders of magnitude smaller than that of the conventional therm oelectric materials. By examining , S and individually, we nd is hopelessly high, while S and are comparable. This is due to the polaron conduction where the mobility is exponentially lowered with decreasing temperature.

Let us discuss the sign change of the therm opower at 500 K .W e should note that the electronic states (and the crystalstructure) of C a_2 (C o, A l_2 O $_5$ resemble those of the cubic perovskite LaC oO $_3$, which is a p-type conductor at all tem peratures [13]. Thus it is very likely that holes are

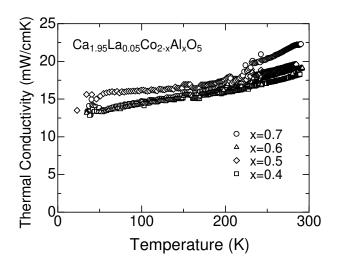


FIG. 5: Thermal conductivity of polycrystalline $Ca_{1:95}La_{0:05}Co_2 \times A \downarrow_{c}O_5$

them ally excited also in C a_2 (C o,A l_2O_5 at high tem perature, which will compensate the doped electrons to decrease the m agnitude of the therm opower. In general, the square lattice as seen in the brownm illerite is offen sym – m etric to electron and hole doping (which is exact in the tight-binding approximation) [14, 15]. This means that electrons and holes are equally excited at high tem per-

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ature to give zero therm opower. Thus the electron-hole sym m etry is unsuitable for good therm oelectrics, which m ight be the reason m ost of the perovskite related oxides are not good therm oelectric m aterials.

IV. SUMMARY

W e successfully prepared an n-type Co oxide m aterial for the st time, although the therm oelectric properties are not satisfactory. The gure of merit at 300 K is of the order of 10 6 K 1 , the low value of which comes from the high resistivity. The high resistivity is ascribed to the polaron conduction suggested by the fact that E is one order of m agnitude larger than E_s. The sign change of the therm opower represents therm alexcitation of holes at high temperatures. Thus it would be less advantageous to design an n-type therm oelectric material by using Co oxides with a corner-shared oxygen octahedron network.

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